L Number	Hits	Search Text	DB	Time stamp
38	5141	semiconductor near laser near diode	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 12:53
39	28	(semiconductor near laser near diode) and passive$3 near3 mode near3 lock$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 13:14
40	23	((semiconductor near laser near diode) and passive$3 near3 mode near3 lock$3) and method	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 12:55
41	17	(semiconductor near laser near diode) and passive$3 near3 resonator	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 13:14
42	6	((semiconductor near laser near diode) and passive$3 near3 resonator) and mode near3 lock$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 13:25
44	8	((passive near3 resonat$3) and mode near3 lock$3) and (align$4 or misalign$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 13:32
45	6	((passive near3 resonat$3) and mode near3 lock$3) and mirror$1 near3 (adjust$4 or rotat$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 13:33
46	1		USPAT	2003/07/27 13:43
47	1		USPAT	2003/07/27 13:44
48	1		USPAT	2003/07/27 13:44
49	1		USPAT	2003/07/27 13:44
50	1		USPAT	2003/07/27 13:45
51	1		USPAT	2003/07/27 13:45
43	33	(passive near3 resonat$3) and mode near3 lock$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:02
52	252	semiconductor near3 ring near3 laser	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 13:53
53	4	(semiconductor near3 ring near3 laser) and (passive$3 near3 mode near3 lock$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 13:55
55	1	((semiconductor near3 ring near3 laser) and passive near3 resonat$3) and mode near3 lock$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 13:55
54	23	(semiconductor near3 ring near3 laser) and passive near3 resonat$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 13:56
56	102	(passive near3 resonat$3) and ((frequency or mode) near3 lock$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:03
57	100011	semiconductor near5 laser	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:04
58	36	((passive near3 resonat$3) and ((frequency or mode) near3 lock$3)) and semiconductor near5 laser	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:09

59	5	"5383198"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:09
60	1	("5383198").PN.	USPAT; US-PGPUB	2003/07/27 14:10
61	31	(laser near3 diode) and ((frequency or mode) near3 lock$3) and passive near3 resonat$3	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:15
62	19	((laser near3 diode) and ((frequency or mode) near3 lock$3) and passive near3 resonat$3) and (align$4 or misalign$4 or realign$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:29
63	6	(semiconductor near3 laser near3 diode) and (passive near3 resonator) and (mode near3 lock$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:34
64	1	(semiconductor near3 laser near3 diode) and (passive near3 resonator) and (self near3 mode near3 lock$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:35
65	3	(passive near3 resonator) and (self near3 mode near3 lock$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:36
66	248	(self near3 mode near3 lock$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:36
67	69	((self near3 mode near3 lock$3)) and laser near diode	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:37
68	1	(((self near3 mode near3 lock$3)) and laser near diode) and perturbation and (misalign$4 or realign$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:38
69	23	(((self near3 mode near3 lock$3)) and laser near diode) and (perturbation or misalign$4 or realign$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/07/27 14:38
-	2609	semiconductor near laser near diode	USPAT; US-PGPUB	2003/07/27 12:53
-	2084	semiconductor adj laser adj diode	USPAT; US-PGPUB	2002/10/19 18:17
-	95	(semiconductor adj laser adj diode) and mode near lock$3	USPAT; US-PGPUB	2002/10/19 18:18
-	51	((semiconductor adj laser adj diode) and mode near lock$3) and passive$3	USPAT; US-PGPUB	2002/10/19 18:18
-	20	((semiconductor adj laser adj diode) and mode near lock$3) and passive$3 near mode near lock$3	USPAT; US-PGPUB	2002/10/19 18:19
-	20	(semiconductor adj laser adj diode) and (passive$3 near mode near lock$3)	USPAT; US-PGPUB	2002/10/19 18:19
-	160	(counterpropagating near (waves or pulses))	USPAT; US-PGPUB	2002/10/19 18:41
-	10	((counterpropagating near (waves or pulses))) and (passive$3 near mode near lock$3)	USPAT; US-PGPUB	2002/10/19 18:47
-	1	(((counterpropagating near (waves or pulses))) and (passive$3 near mode near lock$3)) and (semiconductor near laser near diode)	USPAT; US-PGPUB	2002/10/19 18:44
-	5	(((counterpropagating near (waves or pulses))) and (passive$3 near mode near lock$3)) and (laser near diode)	USPAT; US-PGPUB	2002/10/19 18:44
-	130	(laser near diode) and (passive$3 near mode near lock$3)	USPAT; US-PGPUB	2002/10/19 18:56
-	49	((laser near diode) and (passive$3 near mode near lock$3)) not (saturable adj absorber)	USPAT; US-PGPUB	2002/10/19 18:49

-	16	((((laser near diode) and (passive$3 near mode near lock$3)) not (saturable adj absorber)) and (align$4 or misalign$4)	USPAT; US-PGPUB	2002/10/19 18:50
-	10	misalign$4 and (passive$3 near mode near lock$3)	USPAT; US-PGPUB	2002/10/19 18:56
-	0	misalign$4 near (passive$3 near mode near lock$3)	USPAT; US-PGPUB	2002/10/19 19:00
-	76	self near mode near lock$3	USPAT; US-PGPUB	2002/10/19 19:30
-	0	((self near mode near lock$3) and (laser near diode)) and realign$4	USPAT; US-PGPUB	2002/10/19 19:02
-	5	((self near mode near lock$3) and (laser near diode)) and misalign$4	USPAT; US-PGPUB	2002/10/19 19:02
-	25	(self near mode near lock$3) and (laser near diode)	USPAT; US-PGPUB	2002/10/19 19:06
-	18	((self near mode near lock$3) and (laser near diode)) not (saturable adj absorber)	USPAT; US-PGPUB	2002/10/19 19:30
-	5	(self near mode near lock$3) and ring near cavity	USPAT; US-PGPUB	2002/10/19 19:31
-	185	(laser near diode) and (ring near cavity)	USPAT; US-PGPUB	2002/10/19 19:32
-	62	((laser near diode) and (ring near cavity)) and (mode near lock$3)	USPAT; US-PGPUB	2002/10/19 19:39
-	37	((((laser near diode) and (ring near cavity)) and (mode near lock$3)) and (self or passive$3)	USPAT; US-PGPUB	2002/10/19 19:33
-	22	(((((laser near diode) and (ring near cavity)) and (mode near lock$3)) and (self or passive$3)) not (saturable adj absorber)	USPAT; US-PGPUB	2002/10/19 19:33
-	1	((laser near diode) and (ring near cavity)) and (self near mode near lock$3)	USPAT; US-PGPUB	2002/10/19 19:45
-	2084	semiconductor adj laser adj diode	USPAT; US-PGPUB	2002/10/19 19:46
-	18	(semiconductor adj laser adj diode) and 372/94.ccls.	USPAT; US-PGPUB	2002/10/19 19:51
-	1	((semiconductor adj laser adj diode) and 372/94.ccls.) and (passive$3 near mode near lock$3)	USPAT; US-PGPUB	2002/10/19 19:48
-	0	((semiconductor adj laser adj diode) and 372/94.ccls.) and (self near mode near lock$3)	USPAT; US-PGPUB	2002/10/19 19:48
-	6	((semiconductor adj laser adj diode) and 372/94.ccls.) and (mode near lock$3)	USPAT; US-PGPUB	2002/10/19 19:48
-	99	laser adj diode and 372/94.ccls.	USPAT; US-PGPUB	2002/10/19 19:52
-	1	(laser adj diode and 372/94.ccls.) and self adj mode adj locking	USPAT; US-PGPUB	2002/10/19 19:52
-	6	(laser adj diode and 372/94.ccls.) and passive adj mode adj locking	USPAT; US-PGPUB	2002/10/19 19:55
-	50	(semiconductor adj laser adj diode) and ((ring near cavity) or (ring near laser))	USPAT; US-PGPUB	2002/10/19 19:56
-	1	((semiconductor adj laser adj diode) and ((ring near cavity) or (ring near laser))) and ((self adj mode adj lock$3) or (passive adj mode adj lock$3))	USPAT; US-PGPUB	2002/10/19 19:57